

Growing waves of innovation & productivity growth

1st Wave 1983 Personal computing 2nd Wave 1995 Internet era







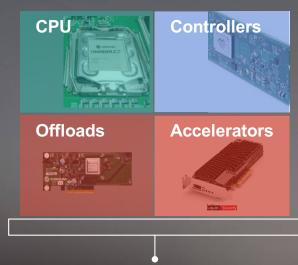
Infrastructure must transform to proliferate Data era



Unprecedented demand & growth velocity



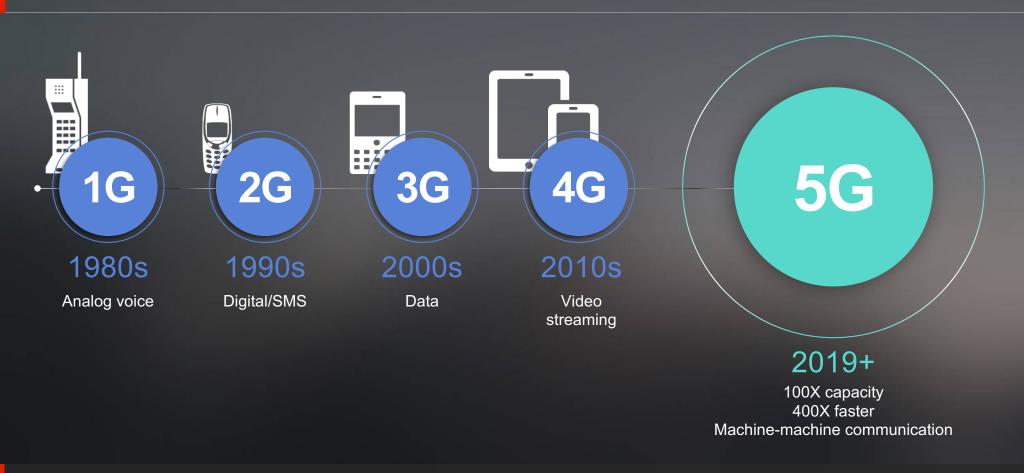
Low latency & data volume is decentralizing the Cloud



Driving the need for optimized architectures

5G & Artificial Intelligence will accelerate transformation

What is 5G?



How 5G will disrupt

Real-time speed

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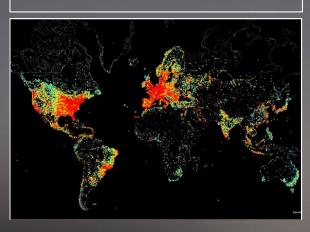
- 5G <1ms (real time)
- 4G/LTE = 200ms
- Human reaction = 300ms

Ultra-high bandwidth



- 5G = 20Gbps
- Stream 400 8K movies at once
- 4G/LTE = 10-20Mbps

Ubiquitous connectivity



- 5G = 1M devices in 1 square km
- 4G/LTE = 1M devices in 500 square km

5G combined with AI will power the Data era



Factory automation



Connected transport & smart vehicles



Industrial IoT & extreme mobile broadband



Immersive experiences

Impact on Flash storage solutions

New SSD protocol interfaces & form factors



New architectures & business models



Optimized platform solutions

Platform-managed Flash
Key-value Flash
Computational storage
Ethernet Bunch of Flash (EBOF)

Disruptive Flash solutions for the Data era

NVMe-oF Ethernet SSDs

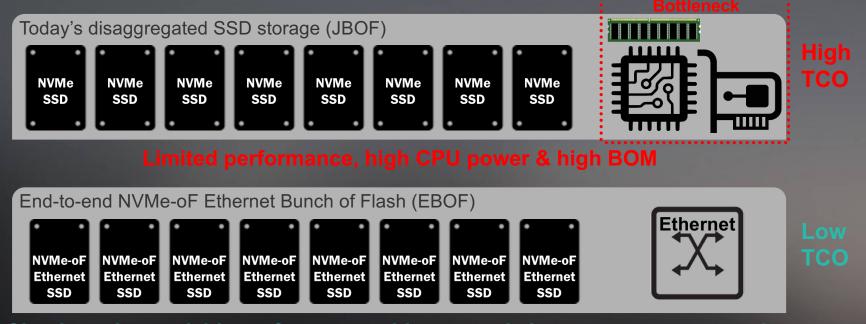
- Cloud data center disaggregated storage
- Enterprise storage systems

DRAMIess m.2230 PCIe Gen4 Form Factor SSDs

- Distributed Edge computing systems
- Client computing platforms

NVMe over Fabric Ethernet SSDs

Disruptive NVMe-oF Ethernet SSD architecture



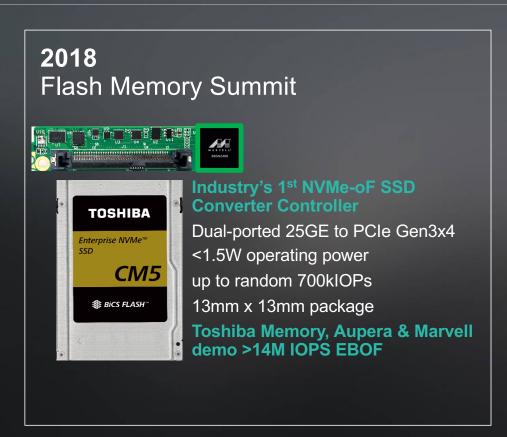
Simple native scalable performance with extremely lower power consumption

>65%* TCO savings excluding SSDs

*Toshiba & Marvell TCO analysis

NVMe-oF Ethernet SSD & EBOF architecture update #1

Industry's 1st 2.5" in-form factor NVMe-oF Ethernet SSD





NVMe-oF Ethernet SSD & EBOF architecture update #2

Industry's 1st 2.5" NVMe-oF Ethernet SSD controller

2018 Flash Memory Summit





Industry's 1st NVMe-oF SSD Converter Controller

Dual-ported 25GE to PCle Gen3x4

<1.5W operating power

13mm x 13mm package

88SS1098 Data Center PCle Gen3x4 SSD controller

Up to 700 kIOPS

17mm x 17mm package

2-chip SSD solution

2019 Flash Memory Summit



Industry's 1st Native NVMe-oF Ethernet SSD Controller

Dual-ported 25GE to eight 800MT/s NAND channels

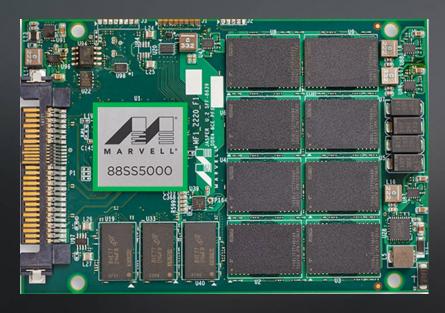
<5W operating power

Up to random 700kIOPs

21mm x 21mm package

Single chip SSD solution

Enabling in-form factor 2.5" NVMe-oF Ethernet SSDs



- Dual-ported 25GE Ethernet
- SFF-8639 / 9639 connector with Ethernet pinout
- Up to 8TB capacity
- Up to random 700kIOPs
- Live at Marvell FMS booth #511

NVMe-oF Ethernet SSD & EBOF architecture update #3

Industry's 1st Storage Aware Flow Engine (SAFE) Ethernet switches

2018 Flash Memory Summit



Prestera® CX 84xx
1.8Tb/s Ethernet Switch Family
10GE, 25GE & 100GE
Multiple configurations & packages

2019 Open Compute Summit



Prestera® CX 85xx

2Tb/s to 12.8 Tb/s Ethernet Switch Family

25GE, 50GE, 100GE & 400GE

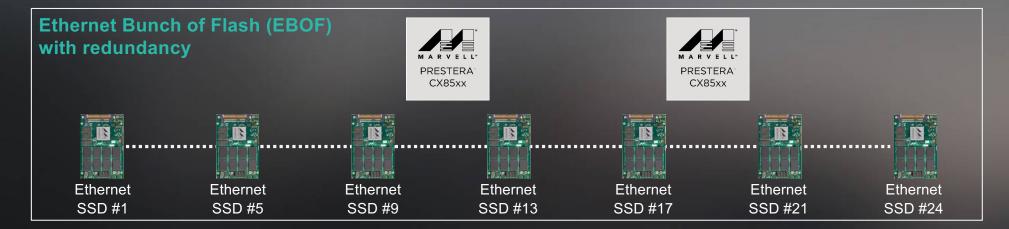
Multiple configurations & packages

Industry's 1st Switches supporting Storage Aware Flow Engine (SAFE) IP

End-to-end NVMe-oF EBOF chipset architecture solution

ThunderX2® ARM Servers & FastLinQ® NVMe-oF NICs





Enabling optimal disaggregated data center flash storage

MARVELL®

DRAMIess m.2230 Form Factor PCIe Gen4 SSDs

Why m.2230 form factor for edge & client computing SSDs?



m.2230

62.5% space saving



- 62.5% space savings
- Lowers power by >30%* with DRAM eliminated
- Capacities up to 1TB** on a single side
- Comparable high sequential & random performance*

^{*} Controller & NAND configuration dependent

^{**} Assumes 1Tb ODP 1200MT/s NAND Package

How? Capitalizing on three NAND component trends

NAND Die Capacity

2015: 128Gb 2019: 512Gb

Up 4x

NAND Interface Speed

2015: 533 MT/s 2019: 1200 MT/s

Up >2.25x

7

NAND Die Planes

2015: 1 plane 2019: 4 planes

Up 4x

Reduced NAND Dies per Equivalent SSD

2015: 16 dies 2019: 4 dies

75% reduction

Mainstream <1TB SSDs will no longer require larger & higher-power 8 channel SSD controllers

Introducing the industry's 1st 12nm PCIe Gen4 NVMe DRAMIess 4CH SSD controllers





- PCle Gen4x4 & PCle Gen4x2
- Four 1200MT/s NAND channels
- Less than 2W* of dissipated power
- Up to 3.9GB/s sequential performance
- Up to 500kIOPS of random performance
- Ultra small 8mm x 11mm package

* Actual power may vary on multiple parameters including temperature, SSD configuration & workload usage

Summary

- 5G & Al will proliferate Data era & require new Flash solutions
- EBOF is optimal flash storage disaggregation architecture
- Ethernet SSDs are here today: Toshiba Memory & Marvell demo
- m.2230 DRAMless SSDs optimal for for edge & client computing
- Industry's 1st 12nm PCIe Gen4 DRAMIess controllers available now

Visit Marvell FMS booth #511 for latest EBOF & Flash innovations
Visit Toshiba Memory booth #307 for industry's 1st 2.5" NVMe-oF Ethernet SSD

M A R V E L L®